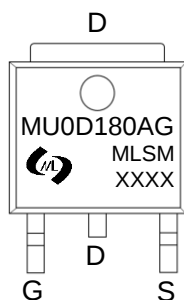


Features

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Split gate trench MOSFET technology
- Fast switching and soft recovery

Application

- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor



MU0D180AG: Device code
 XXXX: Code

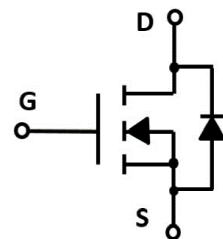
Marking and pin assignment

Product Summary

V_{DS}	$R_{DS(on)}$ TYP	I_D
30V	1.7m Ω @10V	180A
	3.0m Ω @4.5V	



TO-252 view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 180	A

Mounted on Large Heat Sink

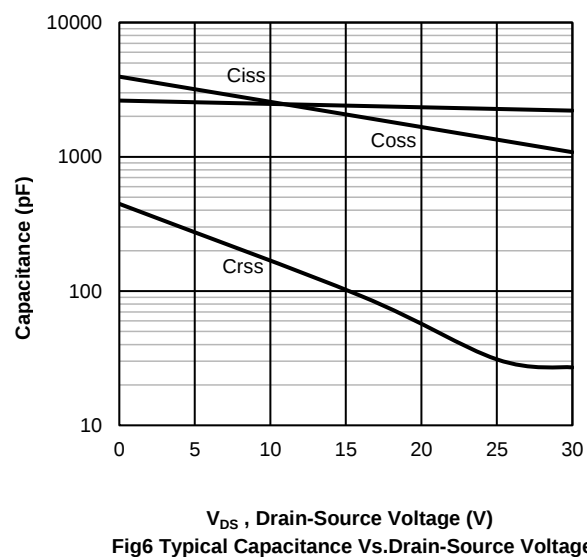
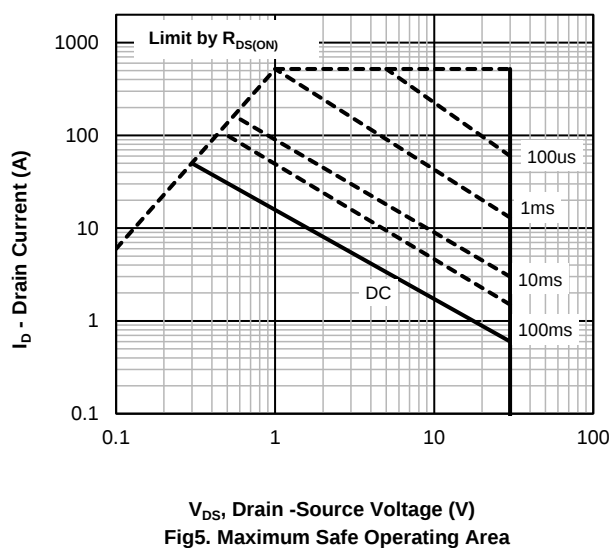
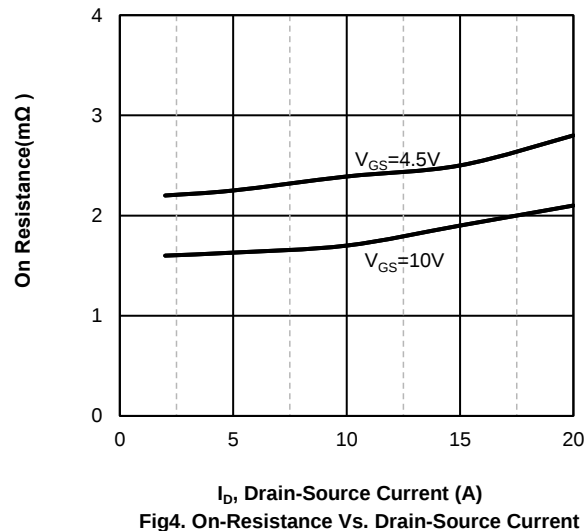
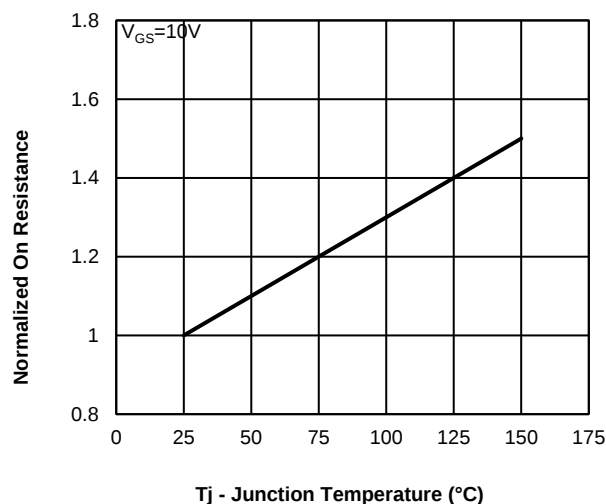
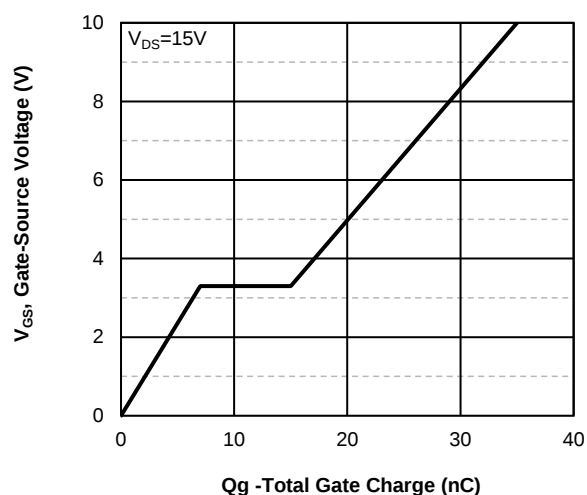
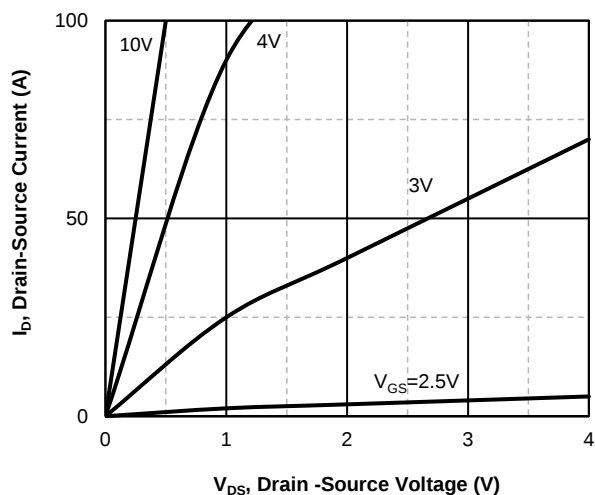
I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ 540	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ 180	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 28	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	48	°C/W

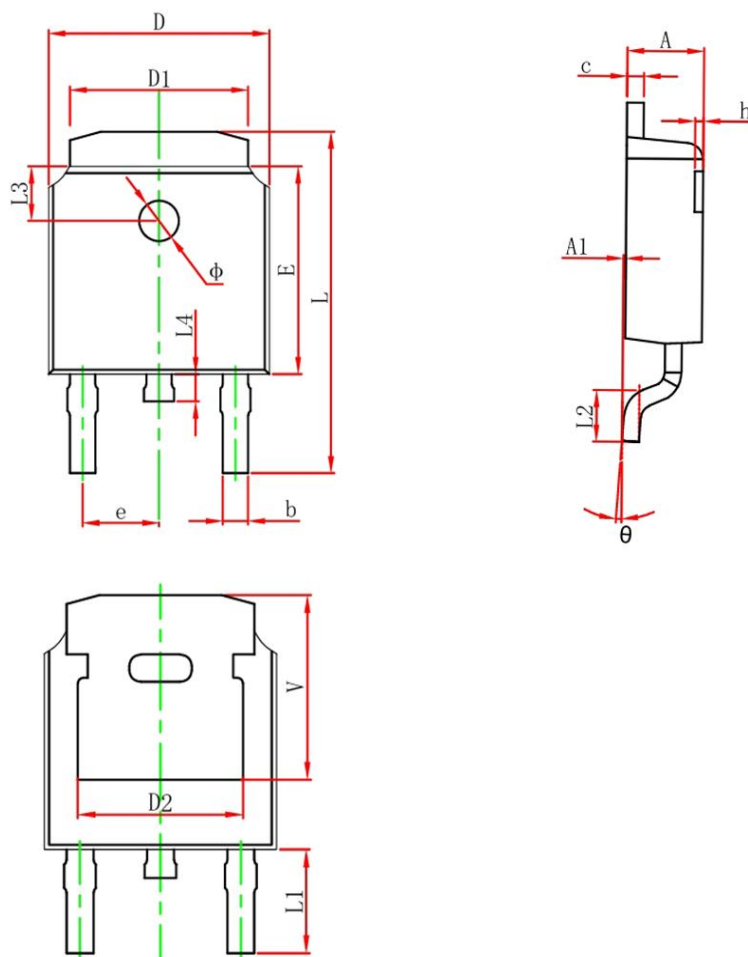
Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MU0D180AG	TO-252	MU0D180AG	2,500	5,000	35,000	13"reel

Electrical Characteristics (T _J =25℃ unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25℃ (unless otherwise stated)						
B _{V(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	--	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =20A	--	1.7	2.4	mΩ
		V _{GS} =4.5V, I _D =15A	--	3.0	3.7	mΩ
Dynamic Electrical Characteristics @ T _J = 25℃ (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	--	2351	--	pF
C _{OSS}	Output Capacitance		--	2164	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	106	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =15V, I _D =20A, V _{GS} =10V	--	36	--	nC
Q _{gs}	Gate Source Charge		--	6.9	--	nC
Q _{gd}	Gate Drain Charge		--	6.4	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =15V, I _D =20A, V _{GS} =10V, R _G =3Ω	--	10	--	nS
t _r	Turn-on Rise Time		--	28	--	nS
t _{d(off)}	Turn-Off Delay Time		--	30	--	nS
t _f	Turn-Off Fall Time		--	9	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25℃, I _S =10A	--	--	1.2	V

Typical Operating Characteristics



TO-252 Package information


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.450	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.386	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	